



2STX2220

High Gain Low Voltage PNP Power Transistor

General features

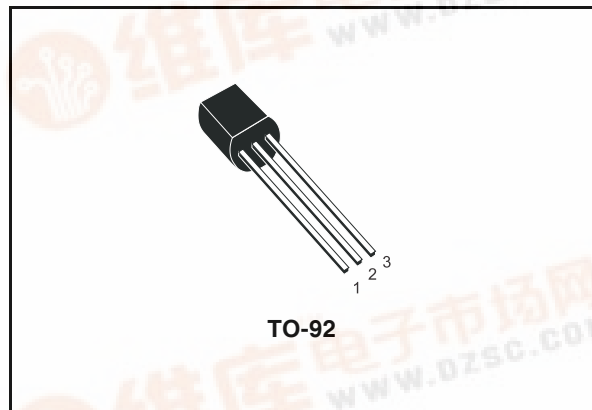
- Very low Collector to Emitter saturation voltage
- D.C. Current gain, $h_{FE} > 100$
- 1.5 A continuous collector current
- In compliance with the 2002/93/EC European Directive

Description

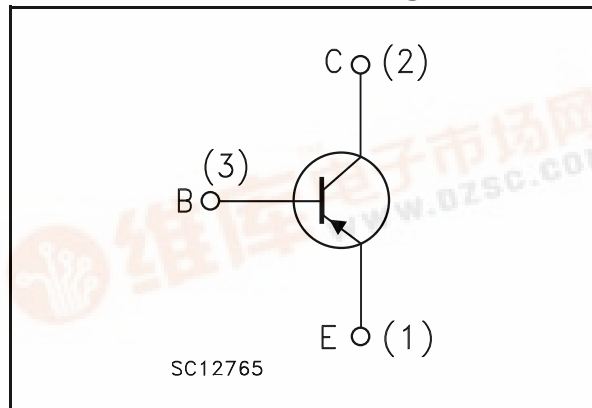
The device in a PNP transistor manufactured using new "PB-HDC" (Power Bipolar High Density Current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

Applications

- Power management in portable equipment
- Switching regulator in battery charger applications



Internal schematic diagram



Order codes

| Part Number | Marking | Package | Packing |
|-------------|---------|---------|---------|
| 2STX2220 | X2220 | TO-92 | Bulk |

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1 Electrical ratings

Table 1. Absolute maximum rating

| Symbol | Parameter | Value | Unit |
|-----------|---|------------|------------------|
| V_{CBO} | Collector-base voltage ($I_E = 0$) | -20 | V |
| V_{CEO} | Collector-emitter voltage ($I_B = 0$) | -20 | V |
| V_{EBO} | Emitter-base voltage ($I_C = 0$) | -5 | V |
| I_C | Collector current | -1.5 | A |
| I_{CM} | Collector peak current ($t_P < 5\text{ms}$) | -3 | A |
| I_B | Base current | -0.1 | A |
| I_{BM} | Base peak current ($t_P < 5\text{ms}$) | -0.2 | A |
| P_{tot} | Total dissipation at $T_{amb} = 25^\circ\text{C}$ | 0.9 | W |
| T_{stg} | Storage temperature | -65 to 150 | $^\circ\text{C}$ |
| T_J | Max. operating junction temperature | 150 | $^\circ\text{C}$ |

Table 2. Thermal data

| Symbol | Parameter | Value | Unit |
|----------------|----------------------------------|----------|--------------------|
| $R_{thj-case}$ | Thermal resistance junction-case | max 44.6 | $^\circ\text{C/W}$ |
| $R_{thj-amb}$ | Thermal resistance junction-amb | max 139 | $^\circ\text{C/W}$ |

2 Electrical characteristics

($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise specified)

Table 3. Electrical characteristics

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|-------------------------------------|--|--|-------------------------|-----------|----------------|---------------|
| I_{CBO} | Collector cut-off current ($I_{\text{E}} = 0$) | $V_{\text{CB}} = -20\text{V}$ | | | -0.1 | μA |
| I_{EBO} | Emitter cut-off current ($I_{\text{C}} = 0$) | $V_{\text{EB}} = -5\text{V}$ | | | -0.1 | μA |
| $V_{(\text{BR})\text{CEO}}^{(2)}$ | Collector-emitter breakdown voltage ($I_{\text{B}} = 0$) | $I_{\text{C}} = -10\text{mA}$ | -20 | | | V |
| $V_{(\text{BR})\text{EBO}}$ | Emitter-base breakdown voltage ($I_{\text{C}} = 0$) | $I_{\text{E}} = -100\mu\text{A}$ | -5 | | | V |
| $V_{\text{CE}(\text{sat})}^{(2)}$ | Collector-emitter saturation voltage | $I_{\text{C}} = -0.5\text{A}$ $I_{\text{B}} = -50\text{mA}$ $I_{\text{C}} = -1.5\text{A}$ $I_{\text{B}} = -150\text{mA}$ | | | -0.25 -0.45 | V V |
| $V_{\text{BE}(\text{sat})}^{(2)}$ | Base-emitter saturation voltage | $I_{\text{C}} = -0.5\text{A}$ $I_{\text{B}} = -50\text{mA}$ $I_{\text{C}} = -1.5\text{A}$ $I_{\text{B}} = -150\text{mA}$ | | | -1 -1.1 | V V |
| $V_{\text{BE}(\text{on})}^{(2)}$ | Base-emitter on voltage | $I_{\text{C}} = -1\text{A}$ $V_{\text{CE}} = -2\text{V}$ | | | -1 | V |
| $h_{\text{FE}}^{(2)}$ | DC current gain | $I_{\text{C}} = -100\text{mA}$ $V_{\text{CE}} = -2\text{V}$ $I_{\text{C}} = -500\text{mA}$ $V_{\text{CE}} = -2\text{V}$ $I_{\text{C}} = -1.5\text{A}$ $V_{\text{CE}} = -2\text{V}$ $I_{\text{C}} = -3\text{A}$ $V_{\text{CE}} = -2\text{V}$ | 200 170 120 75 | | 600 | |
| C_{CBO} | Collector-base capacitance | $I_{\text{E}} = 0$ $V_{\text{CB}} = -10\text{V}$ $f = 1\text{MHz}$ | | 30 | | pF |
| t_{on} t_{off} | Resistive load Turn-on time Turn-off time | $I_{\text{C}} = -1.5\text{A}$ $V_{\text{CC}} = -10\text{V}$ $I_{\text{B}1} = -I_{\text{B}2} = -150\text{mA}$ | | 60 250 | | ns ns |

Note (2) Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 1. Output characteristics

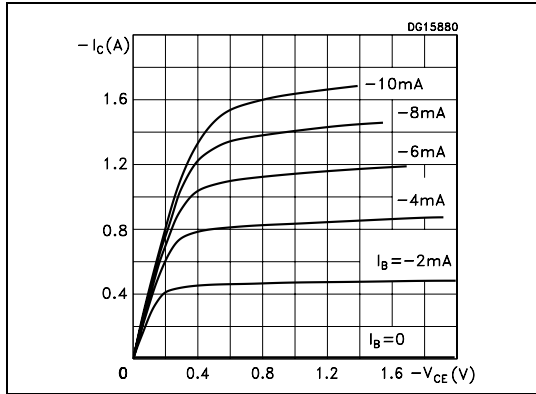


Figure 2. DC current gain

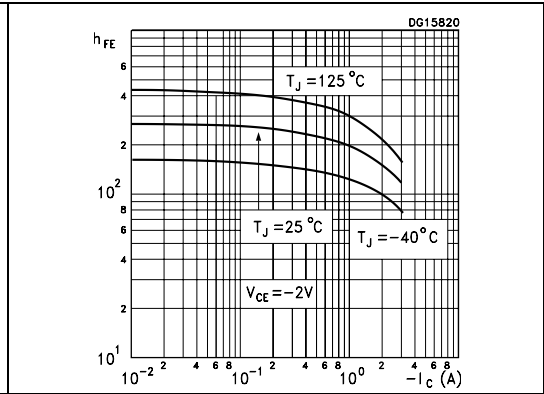


Figure 3. DC current gain

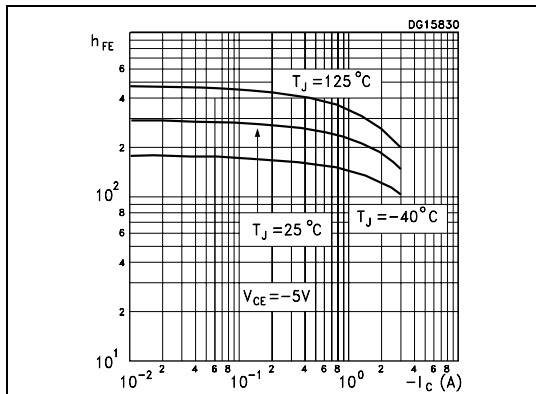


Figure 4. Collector-emitter saturation voltage

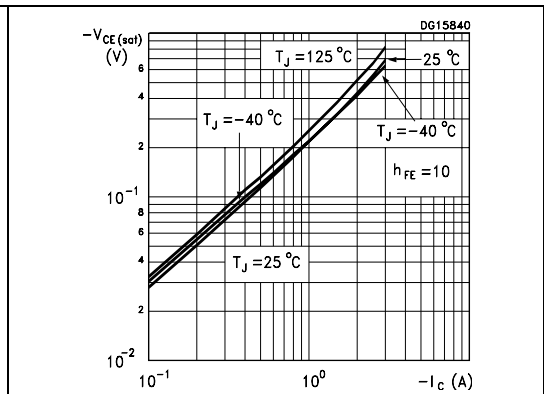


Figure 5. Base-emitter saturation voltage

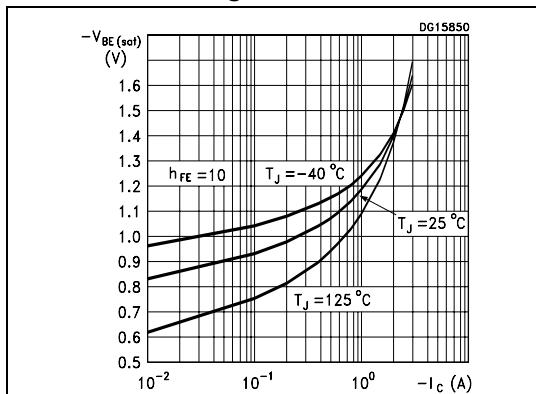


Figure 6. Base-emitter on voltage

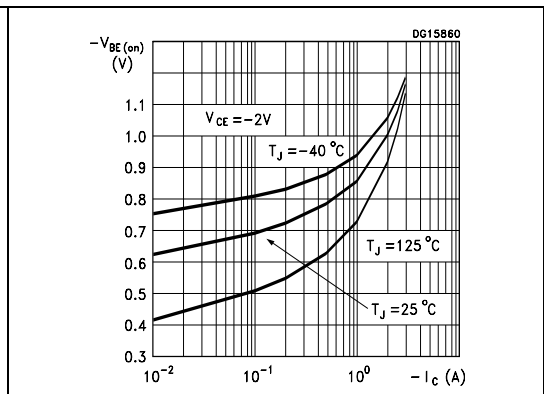


Figure 7. Capacitance curves

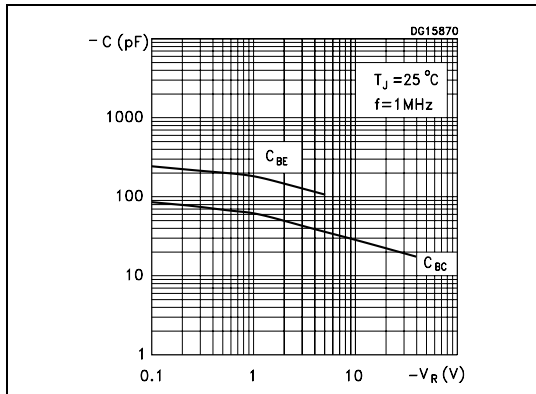


Figure 8. Switching time resistive load

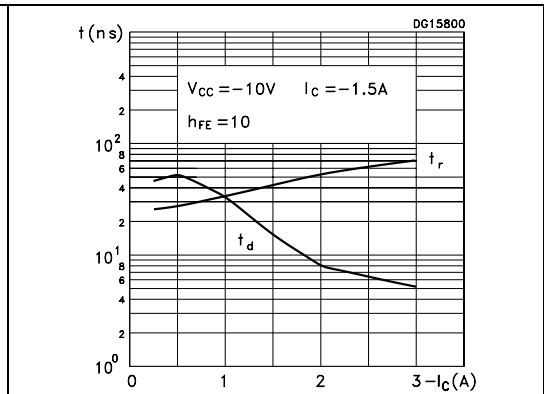
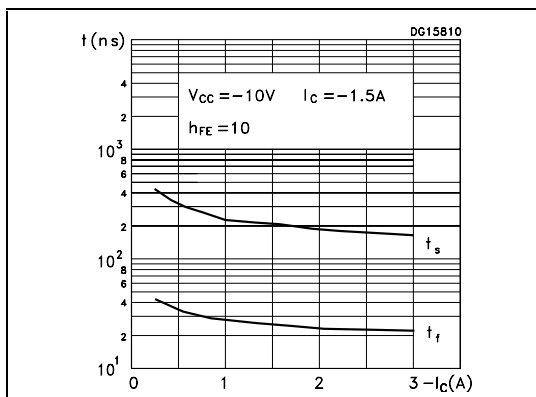
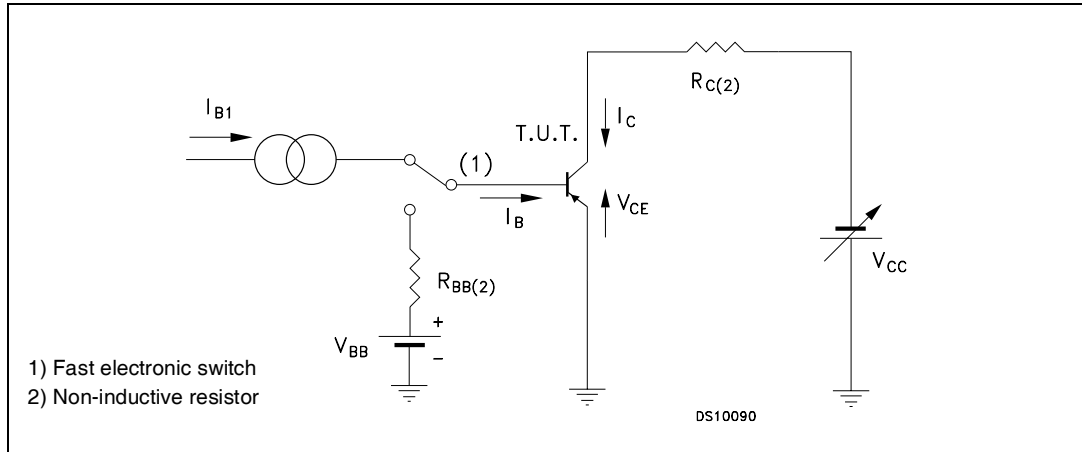


Figure 9. Switching time resistive load



2.2 Test circuits

Figure 10. Resistive load switching test circuit

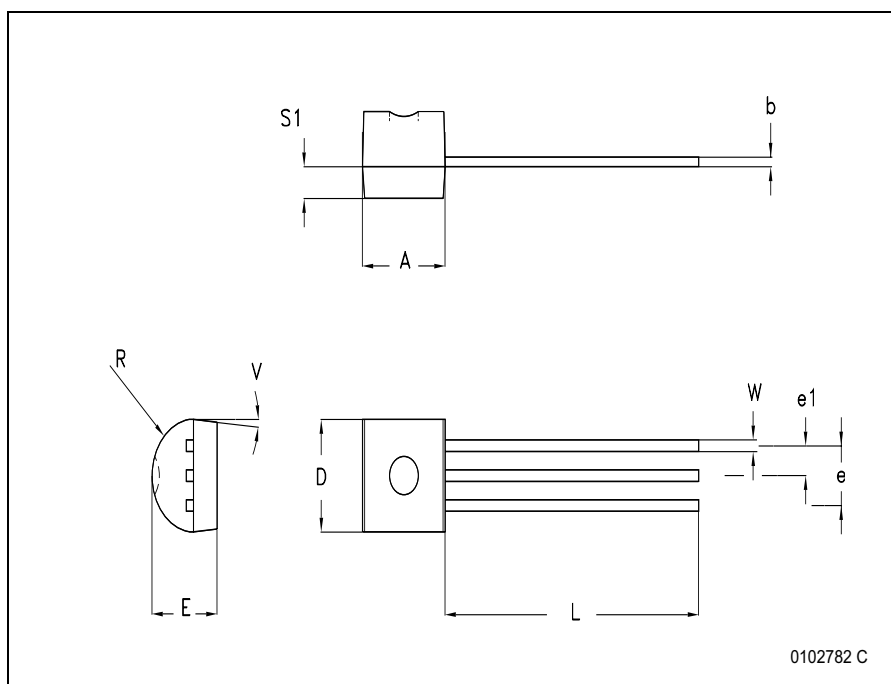


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-92 BULK SHIPMENT MECHANICAL DATA

| DIM. | mm. | | |
|------|-------|-----|-------|
| | MIN. | TYP | MAX. |
| A | 4.32 | | 4.95 |
| b | 0.36 | | 0.51 |
| D | 4.45 | | 4.95 |
| E | 3.30 | | 3.94 |
| e | 2.41 | | 2.67 |
| e1 | 1.14 | | 1.40 |
| L | 12.70 | | 15.49 |
| R | 2.16 | | 2.41 |
| S1 | 0.92 | | 1.52 |
| W | 0.41 | | 0.56 |
| V | | 5° | |



4 Revision history

Table 4. Revision history

| Date | Revision | Changes |
|-------------|-----------------|--------------------|
| 19-Jun-2006 | 1 | Initial release. |
| 25-Sep-2006 | 2 | New maturity code. |

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